NSN 5961-01-072-8579

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-072-8579 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.450 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -90.0 collector to base voltage/static/emitter open and -80.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -15.00 amperes source cutoff current and -5.00 amperes source cutoff current **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 04971-109221 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

NSN 5961-01-072-8579 Transistor - Page 2 of 2



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